# mail

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



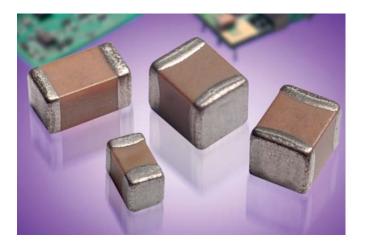
### Contact us

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## **Y5V Dielectric**

#### **General Specifications**

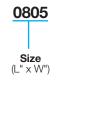


Y5V formulations are for general-purpose use in a limited temperature range. They have a wide temperature characteristic of +22% -82% capacitance change over the operating temperature range of  $-30^{\circ}$ C to  $+85^{\circ}$ C.

These characteristics make Y5V ideal for decoupling applications within limited temperature range.



#### PART NUMBER (see page 2 for complete part number explanation)





50V = 5

**Dielectric** Y5V = G

G

Capacitance Code (In pF) 2 Sig. Digits + Number of Zeros

104



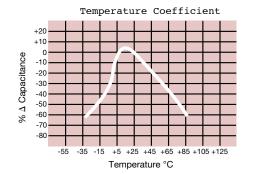
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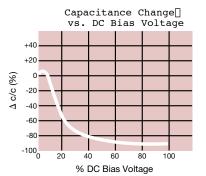


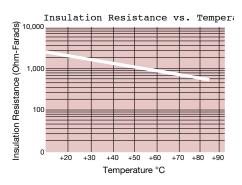


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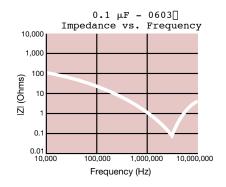
**Special Code** A = Std. Product

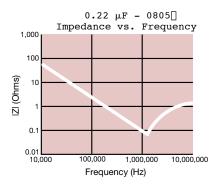


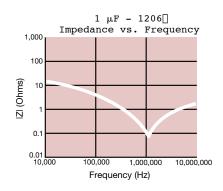




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### **Y5V Dielectric**

### **Specifications and Test Methods**

Parame		Y5V Specification Limits	Measuring Conditions						
<b>Operating Tem</b>	perature Range	-30°C to +85°C	Temperature Cycle Chamber						
Capac		Within specified tolerance		<b>)</b>					
Dissipatio		$\leq$ 5.0% for $\geq$ 50V DC rating $\leq$ 7.0% for 25V DC rating $\leq$ 9.0% for 16V DC rating $\leq$ 12.5% for $\leq$ 10V DC rating	Freq.: 1.0 kHz ± 10% Voltage: 1.0Vrms ± .2V For Cap > 10 µF, 0.5Vrms @ 120Hz						
Insulation I	Resistance	10,000MΩ or 500MΩ - μF,	Charge device with rated voltage for						
Dielectric		whichever is less No breakdown or visual defects	120 ± 5 secs @ room temp/humidity Charge device with 300% of rated voltage for 1-5 seconds, w/charge and discharge current limited to 50 mA (max)						
	Appearance	No defects		on: 2mm					
Resistance to	Capacitance Variation	≤ ±30%		30 seconds 7 1mm/sec					
Flexure Stresses	Dissipation Factor	Meets Initial Values (As Above)							
	Insulation Resistance	$\geq$ Initial Value x 0.1							
Solder	rability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutection for 5.0 ± 0	c solder at 230 ± 5°C .5 seconds					
	Appearance	No defects, <25% leaching of either end terminal							
	Capacitance Variation	$\leq \pm 20\%$	Din device in eutectic	solder at 260°C for 60					
Resistance to Solder Heat	Dissipation Factor	Meets Initial Values (As Above)	seconds. Store at room temperature for $24 \pm 2$ hours before measuring electrical properties.						
oolder neut	Insulation Resistance	Meets Initial Values (As Above)							
	Dielectric Strength	Meets Initial Values (As Above)							
	Appearance	No visual defects	Step 1: -30°C ± 2°	30 ± 3 minutes					
	Capacitance Variation	≤ ±20%	Step 2: Room Temp	≤ 3 minutes					
Thermal Shock	Dissipation Factor	Meets Initial Values (As Above)	Step 3: +85°C ± 2°	30 ± 3 minutes					
	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes					
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles at 24 ±2 hours at room						
	Appearance	No visual defects	Charge device with t	wipp roted vallesse in					
	Capacitance Variation	≤ ±30%	Charge device with t test chamber se	at 85°C ± 2°C					
Load Life	Dissipation Factor	≤ Initial Value x 1.5 (See Above)	for 1000 ho						
	Insulation Resistance	≥ Initial Value x 0.1 (See Above)	Remove from test chamber and stabilize at room temperature for $24 \pm 2$ hours						
	Dielectric Strength	Meets Initial Values (As Above)	before measuring.						
	Appearance	No visual defects	Store in a test chamb	er set at 85°C ± 2°C/					
Laci	Capacitance Variation	≤ ±30%	$85\% \pm 5\%$ relative humidity for 1000 hours (+48, -0) with rated voltage applied.						
Load Humidity	Dissipation Factor	≤ Initial Value x 1.5 (See above)		nber and stabilize at					
	Insulation Resistance	$\geq$ Initial Value x 0.1 (See Above)	room temperature and humidity for $24 \pm 2$ hours before measuring.						
	Dielectric Strength	Meets Initial Values (As Above)		5					

## **Y5V Dielectric**

#### **Capacitance Range**

#### **PREFERRED SIZES ARE SHADED**

					•									1										
SIZI	E	02	201			0402				06	03			080	)5		1206			1210				
Solder	ring	Reflo	w Only		R	eflow/Wa	ave			Reflow	/Wave			Reflow/	Wave			Reflow	/Wave	ive		Reflow Only		
Packag	kaging All Paper			All Paper			All Paper			All P	aper		P	aper/Em	bossed		Paper/Embossed				Paper/Embossed			d
(L) Length	mm (in.)		± 0.09 ± 0.004)	1.00 ± 0.10 (0.040 ± 0.004)			1.60 ± 0.15 (0.063 ± 0.006)					2.01 ± 0.079 ±			3.20 ± 0.20 (0.126 ± 0.008)				3.20 ± 0.20 (0.126 ± 0.008)					
(W) Width	mm (in.)	(0.011	± 0.09 ± 0.004)	0.50 ± 0.10 (0.020 ± 0.004)			.81 ± 0.15 (0.032 ± 0.006)				1.25 ± (0.049 ±	0.008)		1.60 ± 0.20 (0.063 ± 0.008)				2.50 ± 0.20 (0.098 ± 0.008)						
(t) Terminal	mm (in.)	(0.006	± 0.05 ± 0.002)	0.25 ± 0.15 (0.010 ± 0.006)				0.35 ± 0.15 (0.014 ± 0.006)				0.50 ± (0.020 ±			0.50 ± 0.25 (0.020 ± 0.010)				.50 ± 0.25 (0.020 ± 0.010)					
	WVDC	6.3	10	6	10	16	25	50	10	16	25	50	10	16	25	50	10	16	25	50	10	16	25	50
Cap (pF)	820 1000 2200		A A																			$\sim$	-w-	*
Cap (µF)	4700 0.010 0.022	A A	A A																		$\leq$		$\sum$	T
	0.047 0.10 0.22	A		C C				G	G	G	К									let∎				
	0.33 0.47 1.0			С	С	С			G	G G G	G J			N	N	N		М	М	М				N
	2.2 4.7 10.0				С				J				N N	N N P	N N		Q	P Q	K Q X	Q	X	N Q	NQ	
	22.0 47.0																Q				Х	Z		
	WVDC	6.3	10	6	10	16	25	50	10	16	25	50	10	16	25	50	10	16	25	50	10	16	25	50
SIZE		02	201		0402			0603			0805				1206				1210					
Letter	A		c I	E		G	J		K		М	N		Р		Q	Х		Y		7			
Max. Thickness	0.33 (0.013)		56	0.71 0.90 0.94   (0.028) (0.035) (0.037)			1.02 (0.040	02 1.27 1.40		0 1.52 1.78		2.29 2.54 2		2.	79 I 10)									

etter	A	C	E	G	J	K	M	N	Р	Q	Х	Y	Z			
lax.	0.33	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79			
kness	(0.013)	(0.022)	(0.028)	(0.035)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)			
			PAPER			EMBOSSED										